

PROCEEDINGS OF SPIE

***Quantum Dots, Nanostructures, and
Quantum Materials: Growth,
Characterization, and Modeling XVII***

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Editors

**5 February 2020
San Francisco, California, United States**

Sponsored and Published by
SPIE

Volume 11291

Proceedings of SPIE 0277-786X, V. 11291

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Author(s), "Title of Paper," in *Quantum Dots, Nanostructures, and Quantum Materials: Growth, Characterization, and Modeling XVII*, edited by Diana L. Huffaker, Holger Eisele, Proceedings of SPIE Vol. 11291 (SPIE, Bellingham, WA, 2020) Seven-digit Article CID Number.

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510633452

ISBN: 9781510633469 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) Fax +1 360 647 1445

SPIE.org

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